## 2SK2408

### Silicon N-Channel MOS FET

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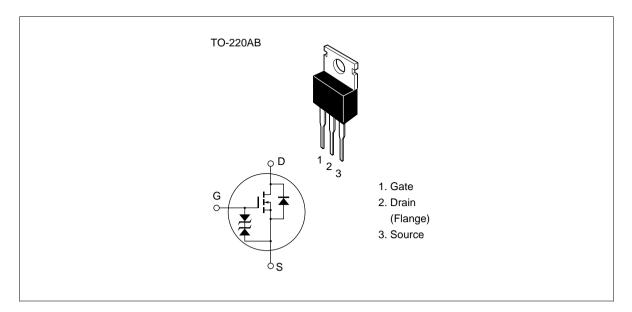
#### Application

High speed power switching

#### Features

- Low on-resistance
- Built-in fast recovery diode ( $t_{rr} = 120$  ns typ)
- High speed switching
- Low drive current
- Suitable for switching regulator, Motor control

#### Outline





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#### **Absolute Maximum Ratings** (Ta = $25^{\circ}$ C)

Item	Symbol	Ratings	Unit V	
Drain to source voltage	V <sub>DSS</sub>	500		
Gate to source voltage	V <sub>GSS</sub>	±30	V	
Drain current	I <sub>D</sub>	7	А	
Drain peak current	I <sup>★1</sup> D(pulse)	28	А	
Body to drain diode reverse drain current	I <sub>DR</sub>	7	А	
Channel dissipation	Pch*2	60	W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Notes 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1 %

2. Value at Tc = 25 °C

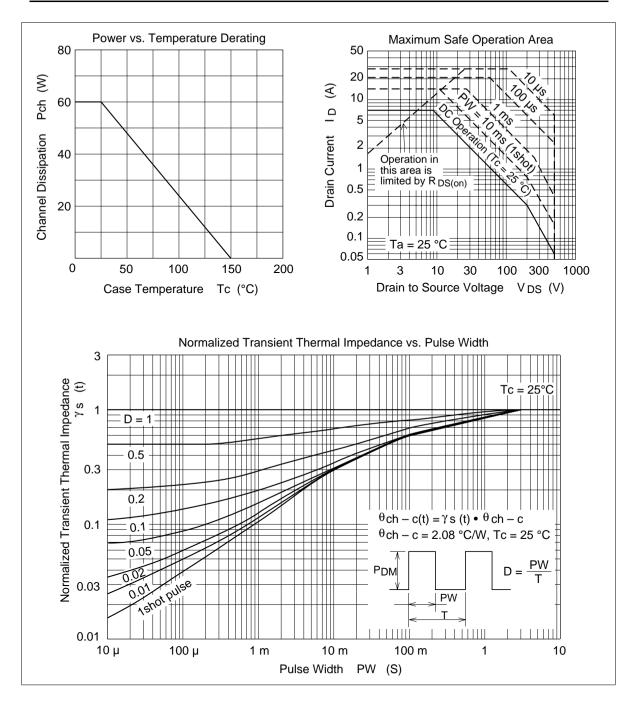
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#### **Electrical Characteristics** (Ta = $25^{\circ}$ C)

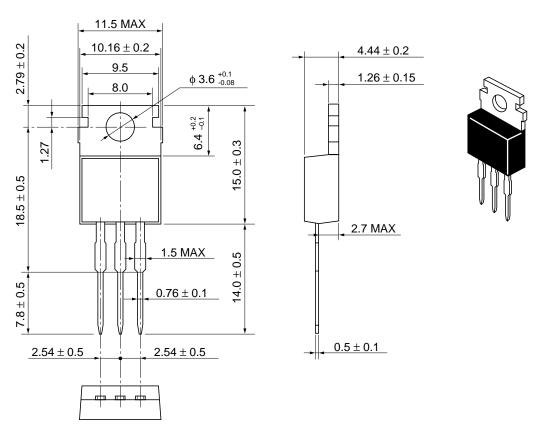
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	500	—	—	V	$I_{\rm D} = 10 \text{ mA}, V_{\rm GS} = 0$
Gate to source breakdown voltage	$V_{(\text{BR})\text{GSS}}$	±30	—	—	V	$I_{g} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 25 \text{ V}, \text{ V}_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_		250	μΑ	$V_{\rm DS} = 400 \text{ V}, \text{ V}_{\rm GS} = 0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	2.0	_	3.0	V	$I_{\rm D} = 1 \text{ mA}, V_{\rm DS} = 10 \text{ V}$
Static drain to source on state resistance	R <sub>DS(on)</sub>	—	0.7	0.9	Ω	$I_{\rm D} = 4A$ $V_{\rm GS} = 10 \ V^{*1}$
Forward transfer admittance	y <sub>fs</sub>	3.5	6.0	—	S	$I_{\rm D} = 4 \text{ A}$ $V_{\rm DS} = 10 \text{ V}^{*1}$
Input capacitance	Ciss	_	1100	_	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss	_	310	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	50		pF	f = 1 MHz
Turn-on delay time	t <sub>d(on)</sub>	_	15		ns	$I_{D} = 4 A$
Rise time	t,	_	55		ns	V <sub>GS</sub> = 10 V
Turn-off delay time	t <sub>d(off)</sub>	_	100		ns	$R_L = 7.5 \Omega$
Fall time	t <sub>f</sub>		48	_	ns	
Body to drain diode forward voltage	$V_{\text{DF}}$	—	0.9	—	V	$I_F = 7 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t <sub>rr</sub>		120	_	ns	$I_F = 7 \text{ A}, V_{GS} = 0,$ $di_F / dt = 100 \text{ A} / \mu \text{s}$

See characteristic curves of 2SK1516

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#### **HITACHI**



Hitachi Code	TO-220AB
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.8 g

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